NSN 5961-01-167-5096

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-167-5096 **Inclosure Material:** Plastic **Overall Length:** 0.770 inches **Terminal Length:** 0.125 inches **Overall Height:** 0.130 inches **Overall Width:** 0.250 inches **Component Name And Quantity:** 5 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 15.0 collector to emitter voltage/static/base open all transistor and 20.0 collector to base voltage/static/emitter open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 750.0 milliwatts small-signal input power, common-collector preset all transistor **Capacitance Rating In Picofarads:** 2.8 all transistor **Maximum Operating Tempurature Per Measurement Point:** 85.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No